

SIC553-04 Photo IC

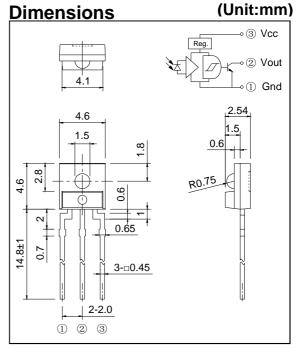
The SIC553-04 is a digital-output detector which incorprates a photodiode with signal processing ciruit(amplifier, Schmitt trigger,voltage regulator).

Features

- Built-in Schmitt trigger circuit
- Open-Collector output
- · Wide Vcc range
- · Low level output without signal

Application

- · Paper sensors
- Optical detectors



MAXIMUM RATINGS

(Ta= 25°C)

Item	Symbol	Rating	Unit	
Supply voltage	Vcc	17	V	
Low level	loL	30	mA	
Out transistor power dissipation	PD	200	mW	
Operating Temperature	Topr.	-25∼+85	$^{\circ}$	
Storage Temperature	Tstg.	-40~+100	$^{\circ}$	
Soldering temperature *1	Tsol.	260	$^{\circ}$	

Note: *1. For MAX.5 seconds at the position of 2mm from the package

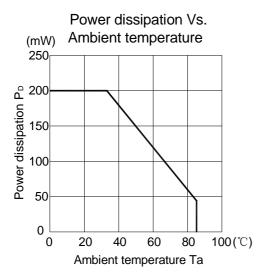
ELECTRO- OPTICAL CHARACTERISTICS

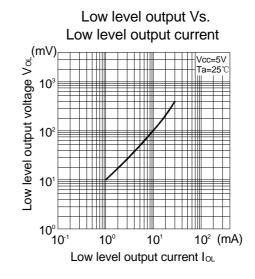
(Ta= 25°C)

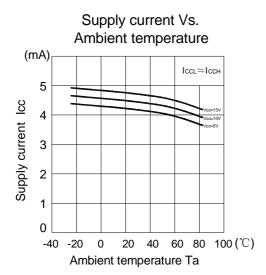
LEEGTING OF HOME SHARAGTERIOTIOS				(1a= 25 c)			
Items		Symbol	Condition	Min.	Тур.	Max.	Unit
Supply voltage		V_{CC}	-	4.5		17	V
High level supply current		I _{CCH}	E _V =200Lux*2	1	3	6	mA
Low level supply current		I _{CCL}	E _V =0Lux	1	3	6	mA
High level output voltage		V_{OH}	RL=10kΩ, Vup=5V E_V =200Lux*2	4.5	-	-	V
Low level o	utput voltage	V_{OL}	I _{OL} =16mA , E _V =0lux	-	-	0.4	V
L→H Threshold illuminance		E_VLH	*2	-	-	65	μW
H→L Threshold illuminance		E_{VHL}	*2	8	-	60	μW
Hysteresis		P_{PLH}/P_{PLH}	-	-	-	0.95	-
Peak wavel	ength	λ_{P}	-	1	900	ı	nm
Switching speed	L→H propagation time	t _{PLH}	E _V =200Lux*2 R _L =280Ω	1	2	6	μS
	H→L propagation time	t _{PHL}		1	3	9	μS
	Rise time	tr		-	0.1	0.5	μS
	Fall time	tf		-	0.05	0.5	μS

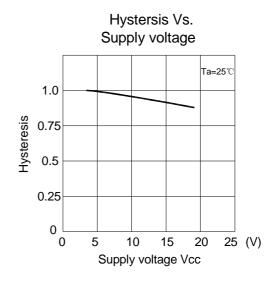
Note: *2. Irradiance by CIE standard light source A (2856K tungsten lamp)

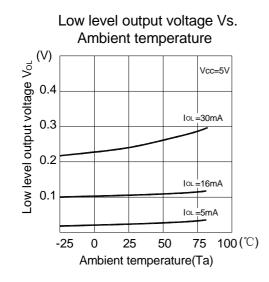
SIC553-04

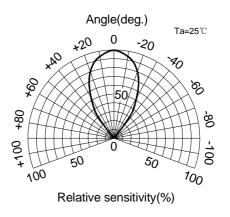












SIC553-04

Packing Specification

- 1. Fixed quantity (1000pcs) of the products are packed into plastic bag
- 2. Five bags of the products are put into #1 box
- 3. Ten #1 boxes are put into #2 box and two #2 boxes are put into #3 box(max 100,000pcs)
- 4. Packing slit is pasted on the out box

